

SS9013

1W Output Amplifier of Potable Radios in Class B Push-pull Operation.

- High total power dissipation. (P_T=625mW)
- High Collector Current. (I_C=500mA)
- Complementary to SS9012
- Excellent h_{FE} linearity.



1. Emitter 2. Base 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	40	V
V _{CEO}	Collector-Emitter Voltage	20	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	500	mA
P _C	Collector Power Dissipation	625	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	40			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 1 \text{mA}, I_B = 0$	20			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \mu A, I_C = 0$	5			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 25V, I_{E} = 0$			100	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 3V$, $I_C = 0$			100	nA
h _{FE1}	DC Current Gain	$V_{CE} = 1V, I_{C} = 50 \text{mA}$ $V_{CF} = 1V, I_{C} = 500 \text{mA}$	64 40	120 120	202	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =500mA, I _B =50mA	40	0.16	0.6	V
V _{CE} (sat)	Base-Emitter Saturation Voltage	I _C =500mA, I _B =50mA		0.10	1.2	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =1V, I _C =10mA	0.6	0.67	0.7	V

h_{FE} Classification

Classification	D	E	F	G	Н
h _{FE1}	64 ~ 91	78 ~ 112	96 ~ 135	112 ~ 166	144 ~ 202

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Typical Characteristics

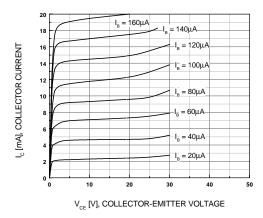


Figure 1. Static Characteristic

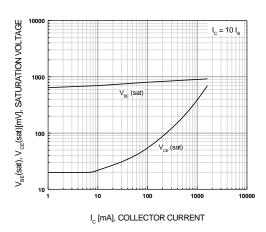


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

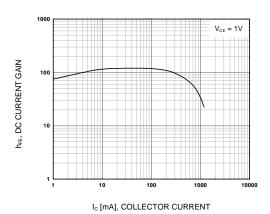


Figure 2. DC current Gain

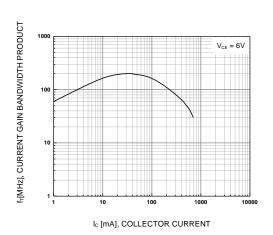


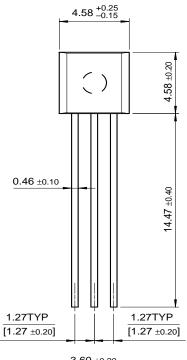
Figure 4. Current Gain Bandwidth Product

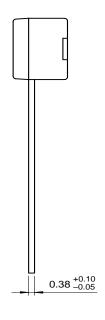
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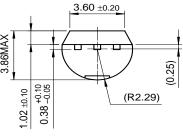
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Package Demensions

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